

Data sheet acquired from Harris Semiconductor SCHS024C – Revised October 2003

CMOS 8-Stage Static Shift Registers

High-Voltage Types (20-Volt Rating) CD4014B:

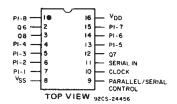
Synchronous Parallel or Serial Input/Serial Output

CD4021B:

Asynchronous Parallel Input or Synchronous Serial Input/Serial Output

■ CD4014B and CD4021B series types are 8-stage parallel- or serial-input/serial output registers having common CLOCK and PARALLEL/SERIAL CONTROL inputs, a single SERIAL data input, and individual parallel "JAM" inputs to each register stage. Each register stage is a D-type, master-slave flip-flop. In addition to an output from stage 8, "O" outputs are also available from stages 6 and 7. Parallel as well as serial entry is made into the register synchronously with the positive clock line transition in the CD4014B. In the CD4021B serial entry is synchronous with the clock but parallel entry is asynchronous. In both types, entry is controlled by the PARALLEL/SERIAL CONTROL input. When the PARALLEL/SERIAL CON-TROL input is low, data is serially shifted into the 8-stage register synchronously with the positive transition of the clock line. When the PARALLEL/SERIAL CONTROL input is high, data is jammed into the 8-stage register via the parallel input lines and synchronous with the positive transition of the clock line. In the CD4021B, the CLOCK input of the internal stage is "forced" when asynchronous parallel entry is made. Register expansion using multiple packages is permitted.

The CD4014B and CD4021b series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

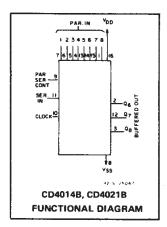


TERMINAL DIAGRAM CD4014B, CD4021B

CD4014B, CD4021B Types

Features:

- Medium-speed operation . . . 12 MHz (typ.) clock rate at VDD-VSS = 10 V
- Fully static operation
- 8 master-slave flip-flops plus output buffering and control gating
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD} = 5 V
 2 V at V_{DD} = 10 V
 2.5 V at V_{DD} = 15 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



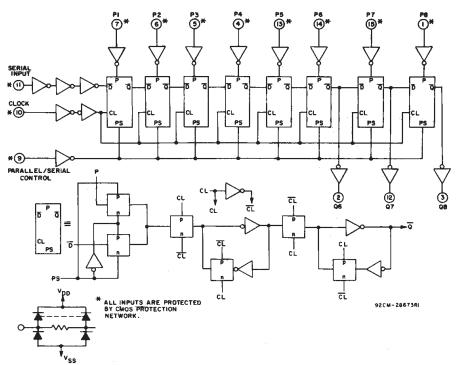
Applications:

- Parallel input/serial output data queueing
- Parallel to serial data conversion
- General-purpose register

RECOMMENDED OPERATING CONDITIONS AT $T_A = 25^{\circ}$ C, Unless Otherwise Specified For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	v _{DD}	LIN	MITS	UNITS
	(V)	Min.	Max.	UNITS
Supply-Voltage Range (T _A = Full Package-Temperature Range)		3	18	V
Clock Pulse Width, t _W	5 10 15	180 80 50	- - -	ns
Clock Frequency, f _{CL}	5 10 15	- - -	3 6 8.5	MHz
Clock Rise and Fall Time, t _F CL, t _f CL	5 10 15	_ _ _	15 15 15	μs
Set-up Time, t _s : Serial Input (ref. to CL)	5 10 15	120 80 60	_ _ _	ns
Parallel Inputs CD4014B (ref. to CL)	5 10 15	80 50 40	- -	ns
Parallel Inputs CD4021B (ref. to P/S)	5 10 15	50 30 20	- -	ns
Parallel/Serial Control CD4014B (ref. to CL)	5 10 15	180 80 60	- -	ns
Parallel/Serial Pulse Width, t _W (CD4021B)	5 10 15	160 80 50	<u> </u>	ns
Parallel/Serial Removal Time, †REM (CD4021B)	5 10 15	280 140 100	- - -	ns

CD4014B, CD4021B Types



TRUTH TABLE — CD4014B

CL SER PARSER PL-1 PL-1 Q1 (INTER NAL)

X 1 0 0 0 0 0

X 1 1 0 1 0 1

X 1 0 1 0 1

X 1 1 1 1 1 1 1

0 0 0 X X 0 Qn-1

1 0 X X 1 Qn-1

X X X X X Q1 Qn NC

X - DON'T CARE CASE

NC - NO CHANGE

Fig. 1 - Logic diagram for CD4014B.

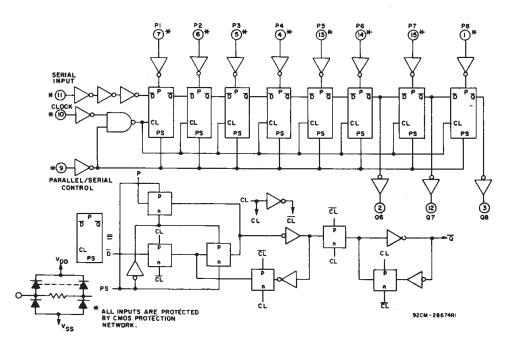


Fig. 2 - Logic diagram for CD40218.

TRUTH TABLE - CD4021B

CL	Serial Input	Parallel/ Serial Control	PI-1	Pl-n	Q ₁ (Internal)	an
х	×	1	0	0	0	0
х	х	1	0	1	0	1
х	х	1	1	0	1	0
х	х	1	1	1	1	1
<u></u>	0	0	х	х	0	Q _n 1
_	1	0	х	x	1	Q _n -1 Q _n -1
_	х	0	х	х	Ω1	an
			X = DO	N'T CA	RE CASE	

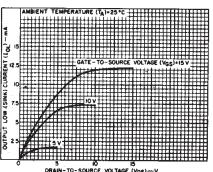
CD4014B, CD4021B Types.

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	and the second s
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	+0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (Pn):	
For T _A = -55°C to +100°C	500mW
For TA = +100°C to +125°C	ate Linearity at 12mW/ ^O C to 200mW
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Type	es)100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Taig). LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ inch $(1.59 \pm 0.79$ mm) from case for 10s max	+265°C

- 1		١	щ	н	н	н	н	П	Ŧ	H	4	Ŧ	П	4	П	П	4	н	T.	Т	п	I	п	7	Е	ш	П	I	П	1	п	J	u	ш	п	ш	1
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- 1	₩.	25	ж	н	н	н	-	н	+	н	+	٠	н	+	н	ч	Ŧ	₩	+	+	₩	+	н	+	+	+	₩	+	₩	+	₩	4	н	-	++	4	4
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- 1	DUTPUT		п	7	П	п	г	т	т,	п	т	П	П	T	н	т	1	п	_	11	7	Ť	Ħ	+	Н	1	H	+	H	+	н	+	11	1	11	+	1
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AMBIENT TEMPERATURE (TA)+25°C

Fig. 3 - Typical output low (sink) current characteristics.



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characteristics.

Fig. 4 - Minimum output low (sink) current

Fig. 5 - Typical output high (source) current characteristics.

DRAIN-TO-SOURCE VOLTAGE (VDS)-V

DRAIN-TO-SOURCE VOLTAGE (VDS)-V

Fig. 6 - Minimum output high (source) current characteristics.

CHARAC- TERISTIC	CON	IDITIO	NS	·LI	MITS AT	INDICA	TED TEI	MPERA	PERATURES (°C)				
	Vo	VIN	v _{DD}			,			+25		s		
	(v) ∵	(V)	(v)	-55	-40	+85	+125	Min.	Тур.	Max.			
Quiescent		0,5	5	5	5	150	150	-	0.04	5			
Device		0,10	10	10	10	300	300	_	0.04	10	μА		
Current,		0,15	15	20	20	600	600	-	0.04	20			
I DD Max.		0,20	20	100	100	3000	3000	_	0.08	100			
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-			
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-			
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-			
Output High	4.6	0,5	5	-0.64	-0.61	-0,42	0.36	-0.51	-1		mΑ		
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_			
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	_	д•		
IOH WIIII	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_			
Output Voltage:		0,5	5		0	.05		-	0	0.05	П		
Low-Level,	agent.	0,10	10		0	.05		_	0	0.05			
V _{OL} Max.	_	0,15	15		0.	.05		-	. 0	0.05	v		
Output	_	0,5	5		4.	95		4.95	- 5	-			
Voltage: High-Level,	_	0,10	10		9	.95		9.95	10	-			
VOH Min.	_	0,15	15		14	.95		14.95	15	-			
Input Low	0.5,4.5	-	5			1.5		-	-	1.5			
Voltage	1,9		10			3		_	_	3			
V _{IL} Max.	1.5,13.5		15			4		_	_	4	v		
Input High	0.5,4.5	-	5		3	3.5		3.5	_	_			
Voltage, 1,9 - 10					7	•	7	_	-				
V _{IH} Min. 1.5,13.5 – 15					11		11	-	-				
Input Current I _{IN} Max.	_	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ		

CD4014B, CD4021B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A=25°C, Input $\rm t_r, t_f$ =20 ns, C_=50 pF, R_1=200 K Ω

	CONI	EST DITIONS		LIMIT	s	
CHARACTERISTIC		(V)	Min.	Тур.	Max.	UNITS
Propagation Delay Time,		- 5	_	160	320	
tPLH, tPHL	1	10	-	80	160	ns
PLH, PHL		15	_	60	120	
Transition Time.		5		100	200	
tTHL, tTLH		10	-	50	100	ns
THEFTER		15		40	80	
Maximum Clock Input	1	5	3	6	_	
Frequency, f _{CL}	1	10	6	12	_	MHz
- reduction, ICE	1	15	8.5	17	_	
Minimum Clock Pulse		. 5		90	180	
Width, tw		10	-	40	80	ns
···otii, tw		15		25	50	
Clock Rise and Fall Time,		5	_	_	15	
t _r CL, t _f CL*		10		_	15	μs
<u> </u>		15		_	15	<u>'</u>
Minimum Set-up Time, ts:		5		60	120	
Serial Input		10		40	80	ns
(ref. to CL)		15		30	60	
Parallel Inputs		5	_	40	80	
CD4014B	İ	10	_	25	50	ns
(ref. to CL)		15	,	20	40	
Parallel Inputs		5		25	50	
CD4021B		10	_	15	30	ns
(ref. to P/S)		15		10	20	
Parallel/Serial Control		5	_	90	180	
CD4014B		10		40	80	ns
(ref. to CL)		15	_	30	60	
Minimum Hold Time, tH:		5	_		0	
Serial In, Parallel In,		10	_	l – i	0 -	ns
Parallel/Serial Control		15	_	_	0	
Minimum P/S Pulse Width,		5		80	160	
twn ·		10	-	40	80	ns
(CD4021B)		15	-	25	50	
Minimum P/S Removal Time,		5		140	280	
tREM		10	_	70	140	ns
CD4021B (ref. to CL)		15	- 1	50	100	-
Average Input Capacitance, C	Anv	Input	_	5	7.5	ρF

^{*} If more than one unit is cascaded t_rCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

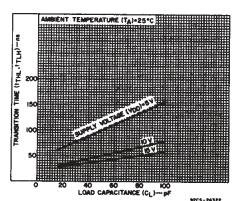


Fig. 7 — Typical transition time as a function of load capacitance.

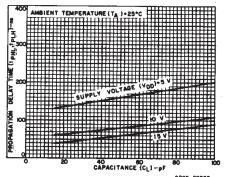


Fig. 8 — Typical propagation delay time as a function of load capacitance.

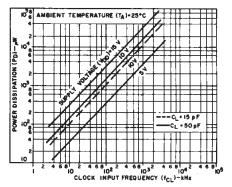


Fig. 9 — Typical dynamic power dissipation
as a function of clock input frequency.

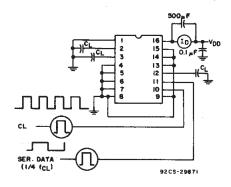


Fig. 10 - Dynamic power dissipation test circuit.

CD4014B, CD4021B Types

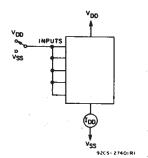


Fig. 11 — Quiescent device current test circuit.

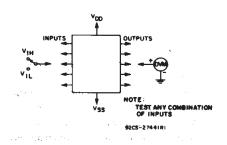


Fig. 12 - Input voltage test circuit.

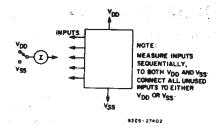
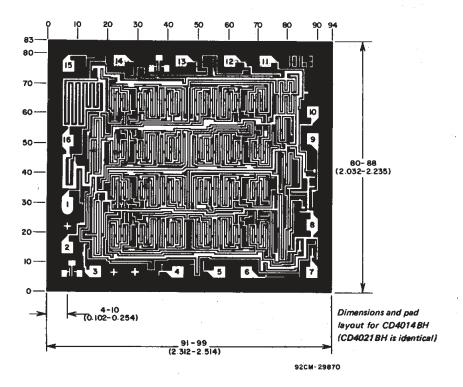


Fig. 13 - Input current test circuit.



Dimensions in perentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4014BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4014BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4014BF3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4014BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BMTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4014BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4021BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4021BF	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4021BF3A	ACTIVE	CDIP	J	16	1	TBD		N / A for Pkg Type
CD4021BF3AS2283	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI
CD4021BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

www.ti.com 12-Jan-2010

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
						no Sb/Br)		
CD4021BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BMTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4021BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
JM38510/05754BEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

www.ti.com 12-Jan-2010

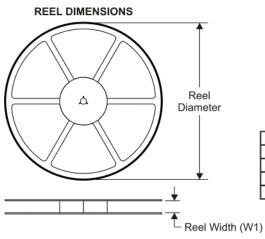
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PACKAGE MATERIALS INFORMATION

www.ti.com 29-Jul-2009

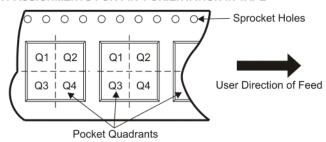
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO BO Cavity AO Cavity

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All dimensions are nomina	l											
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4014BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4014BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
CD4021BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4021BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4021BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1

www.ti.com 29-Jul-2009



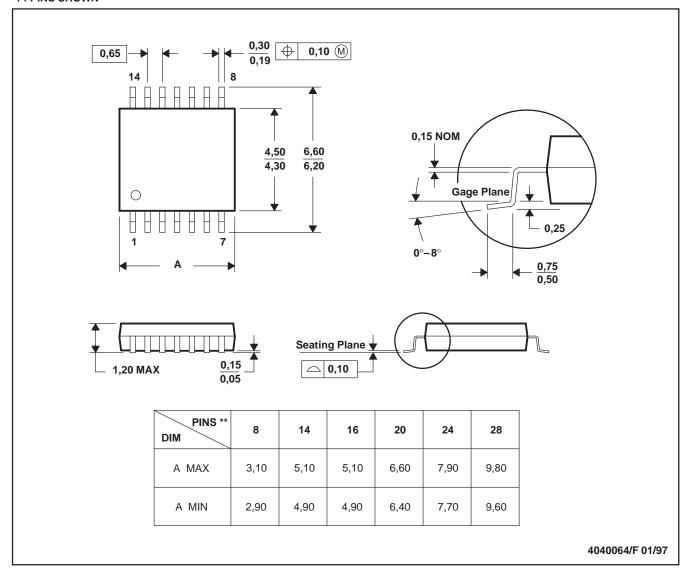
*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4014BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4014BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
CD4021BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4021BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4021BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE

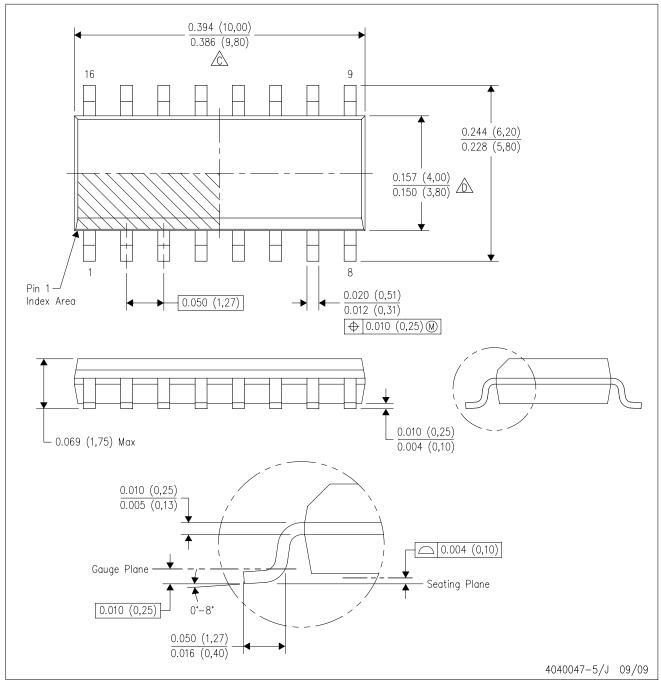


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



D (R-PDS0-G16)

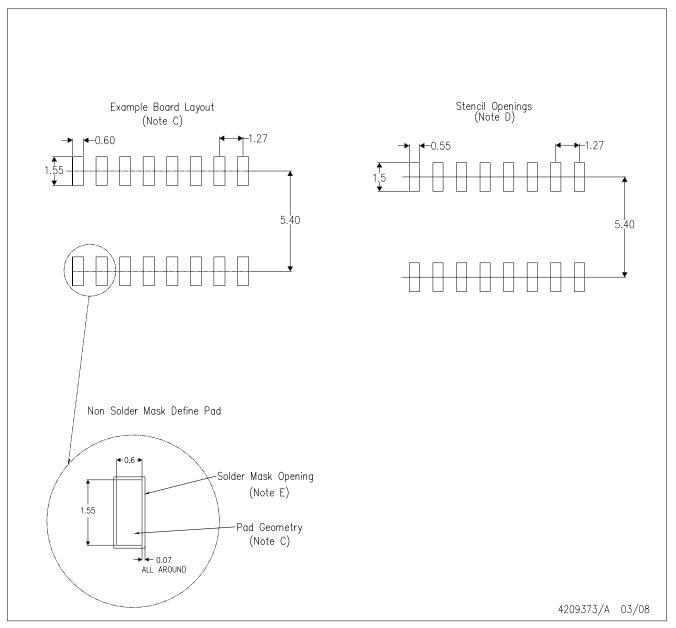
PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



8-Sep-2023 www.ti.com

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4014BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4014BE	Samples
CD4014BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4014BF3A	Samples
CD4014BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4014BM	Samples
CD4014BPW	LIFEBUY	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM014B	
CD4014BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM014B	Samples
CD4021BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4021BE	Samples
CD4021BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4021BE	Samples
CD4021BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4021BF	Samples
CD4021BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4021BF3A	Samples
CD4021BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4021BM	Samples
CD4021BM96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4021BM	Samples
CD4021BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM021B	Samples
JM38510/05754BEA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05754BEA	Samples
M38510/05754BEA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05754BEA	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

PACKAGE OPTION ADDENDUM

www.ti.com 8-Sep-2023

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4014B, CD4014B-MIL, CD4021B, CD4021B-MIL:

Catalog: CD4014B, CD4021B

Automotive: CD4021B-Q1, CD4021B-Q1

Military: CD4014B-MIL, CD4021B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE OPTION ADDENDUM

www.ti.com 8-Sep-2023

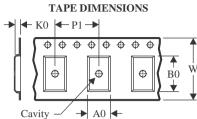
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 12-May-2023

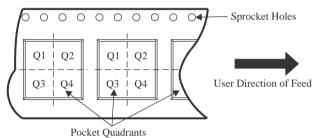
TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

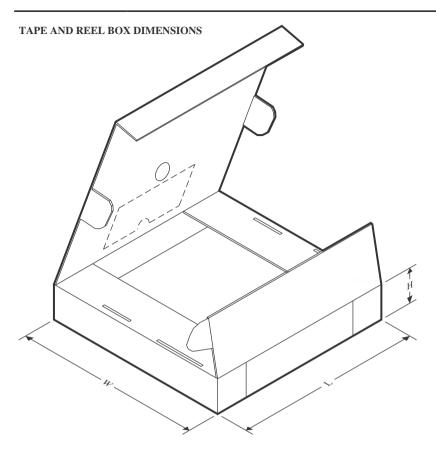


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4014BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4014BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4021BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4021BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 12-May-2023



*All dimensions are nominal

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	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	CD4014BM96	SOIC	D	16	2500	340.5	336.1	32.0
	CD4014BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
ı	CD4021BM96	SOIC	D	16	2500	340.5	336.1	32.0
	CD4021BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4014BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4014BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4014BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4021BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4021BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4021BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4021BEE4	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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